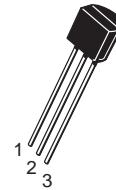
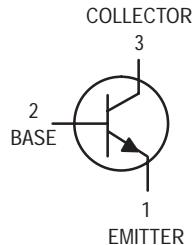


Chopper Transistor

NPN Silicon

MPSA17

Motorola Preferred Device



CASE 29-04, STYLE 1
TO-92 (TO-226AA)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	40	Vdc
Emitter-Base Voltage	V_{EBO}	15	Vdc
Collector Current - Continuous	I_C	100	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.0 8.0	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	$^\circ\text{C/W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	125	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				

Collector-Emitter Breakdown Voltage ($I_C = 1.0 \text{ mA}, I_B = 0$)	$V_{(BR)CEO}$	40	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = 0.1 \text{ mA}, I_C = 0$)	$V_{(BR)EBO}$	15	—	Vdc
Collector Cutoff Current ($V_{CB} = 30 \text{ Vdc}, I_E = 0$)	I_{CBO}	—	100	nAdc
Emitter Cutoff Current ($V_{EB} = 10 \text{ Vdc}, I_C = 0$)	I_{EBO}	—	100	nAdc

Preferred devices are Motorola recommended choices for future use and best overall value.

(Replaces MPSA16/D)

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain ($I_C = 5.0 \text{ mA}_\text{dc}$, $V_{CE} = 10 \text{ V}_\text{dc}$)	h_{FE}	200	600	—
Collector-Emitter Saturation Voltage ($I_C = 10 \text{ mA}_\text{dc}$, $I_B = 1.0 \text{ mA}_\text{dc}$)	$V_{CE(\text{sat})}$	—	0.25	V_dc
SMALL-SIGNAL CHARACTERISTICS				
Current-Gain — Bandwidth Product ($I_C = 5.0 \text{ mA}_\text{dc}$, $V_{CE} = 10 \text{ V}_\text{dc}$, $f = 100 \text{ MHz}$)	f_T	80	—	MHz
Output Capacitance ($V_{CB} = 10 \text{ V}_\text{dc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	C_{obo}	—	4.0	pF

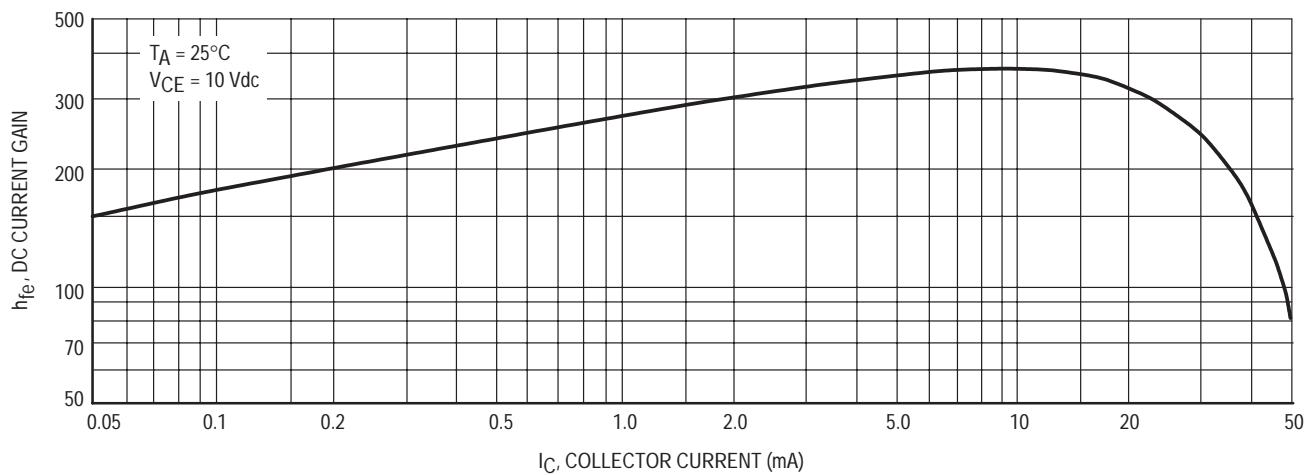


Figure 1. DC Current Gain

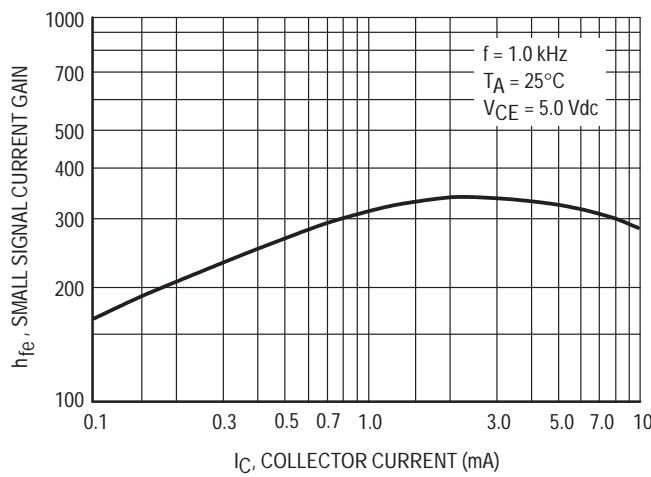


Figure 2. Small Signal Current Gain

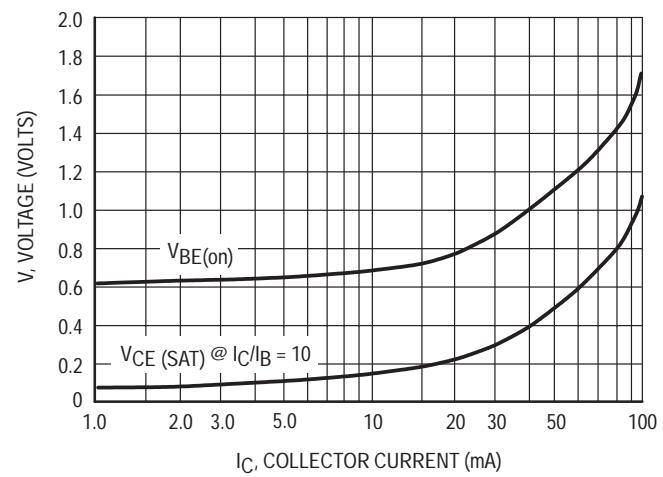


Figure 3. Saturation and On Voltages

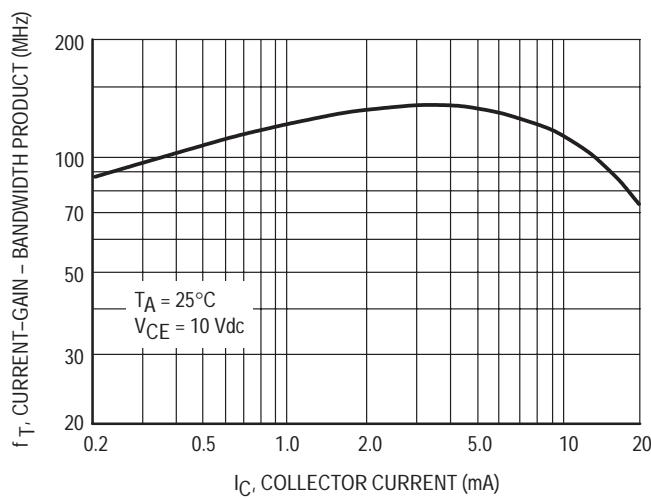


Figure 4. Current—Gain — Bandwidth Product

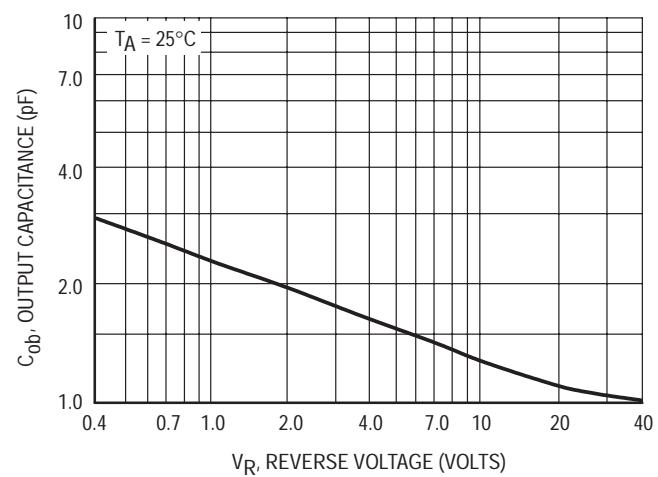


Figure 5. Output Capacitance